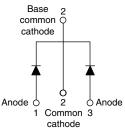


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Schottky Rectifier, 2 x 20 A





PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 20 A				
V _R	20 V				
V _F at I _F	0.34 V				
I _{RM} max.	310 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	18 mJ				

FEATURES

- 150 °C T_J operation
- Optimized for 3.3 V application
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



- RoHS COMPLIANT HALOGEN FREE
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for ultralow forward voltage drop specifically for 3.3 V output power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	40	A		
V _{RRM}		20	V		
I _{FSM}	t _p = 5 μs sine	1000	A		
V _F	20 A _{pk} , T _J = 125 °C	0.34	V		
TJ		- 55 to 150	°C		

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-47CTQ020PbF	VS-47CTQ020-N3	UNITS		
Maximum DC reverse voltage	V _R	20	20	V		
Maximum working peak reverse voltage	V _{RWM}	20	20	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum averageper legforward currentper device			50.% duty evole at T = 125 °C	rootongular wavaform	20			
		I _{F(AV)}	50 % duty cycle at T _C = 135 °C, rectangular waveform		40]		
Maximum peak one cycle no	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse Following any rated lo condition and with rate		1000	A		
surge current per leg		IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	250			
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 3 mH		18	mJ		
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		3	А		

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			
		20 A	T 05 %C	0.45		
		40 A	T _J = 25 °C	0.51		
	V (1)	20 A	T 105.00	0.34		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	- T _J = 125 °C	0.44	V	
		20 A	T 150 %C	0.31		
		40 A	- T _J = 150 °C	0.42		
	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = 5 V	60		
			V _R = 3.3 V	45		
Maximum reverse leakage current per leg		T _J = 150 °C	V _R = 10 V	306	mA	
		T _J = 25 °C	V Deted V	3		
		T _J = 125 °C	$V_{R} = Rated V_{R}$	310		
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.188	V	
Forward slope resistance	r _t			5.9	mΩ	
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz) 25 °C	3000	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		5.5	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

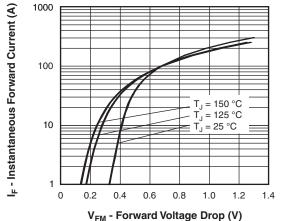
Note

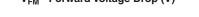
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

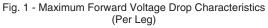
THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	!	T _J , T _{Stg}		- 55 to 150	°C			
Maximum thermal resistance, junction to case per leg		Р		1.5				
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	0.75	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque –	maximum			12 (10)	(lbf · in)			
Marking device			Case style TO-220AB	47CT	Q020			



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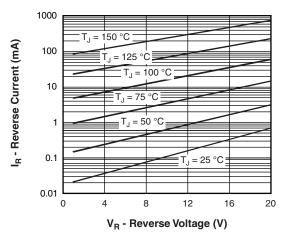


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

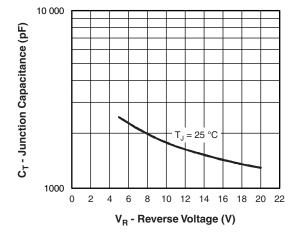
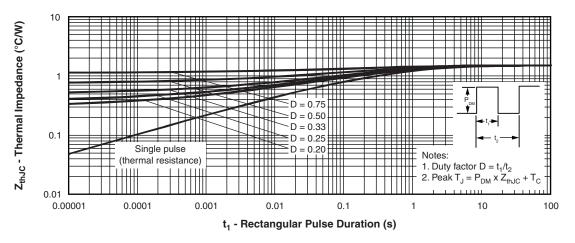


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

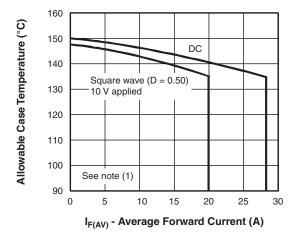


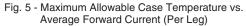


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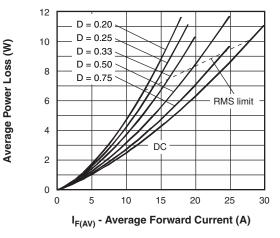


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

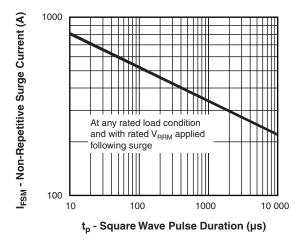


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

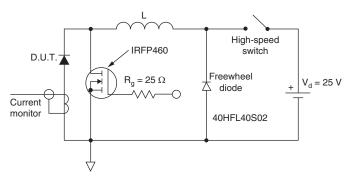


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward \ power \ loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see \ fig. \ 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse \ power \ loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = 10 \ \mathsf{V} \end{array}$

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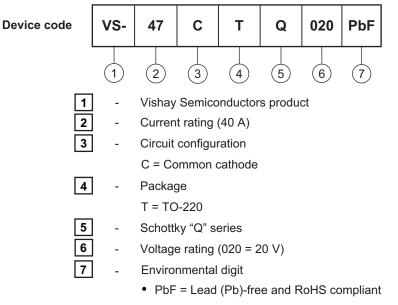
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ORDERING INFORMATION TABLE



• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-47CTQ020PbF	50	1000	Antistatic plastic tube			
VS-47CTQ020-N3	50	1000	Antistatic plastic tube			

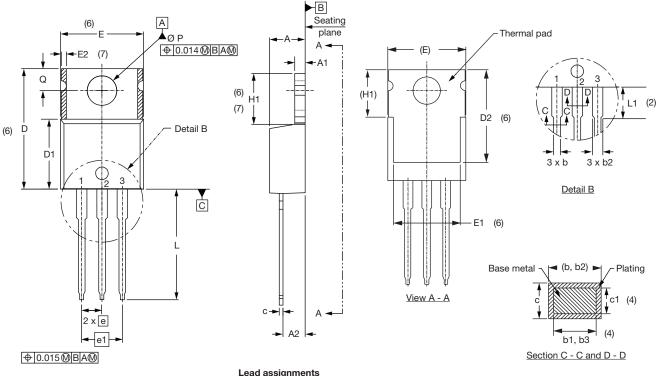
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			

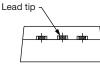


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TO-220AB

DIMENSIONS in millimeters and inches





Leau	l as	sign	en	U
		-		

Diodes 1. - Anode/open

2. - Cathode 3. - Anode

		IETERS	INC	HES	
SYMBOL			_	-	NOTES
	MIN.	MAX.	MIN.	MAX.	
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed $0.127 \text{ mm} (0.005^{\circ})$ per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NUTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- Outline conforms to JEDEC TO-220, except A2 (maximum) and (8) D2 (minimum) where dimensions are derived from the actual package outline

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